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M185-2.5/LM285-2.5/LM385-2.5 Micropower Voltage Reference Diode



# LM185-2.5/LM285-2.5/LM385-2.5 Micropower Voltage Reference Diode

## **General Description**

The LM185-2.5/LM285-2.5/LM385-2.5 are micropower 2-terminal band-gap voltage regulator diodes. Operating over a 20  $\mu A$  to 20 mA current range, they feature exceptionally low dynamic impedance and good temperature stability. On-chip trimming is used to provide tight voltage tolerance. Since the LM-185-2.5 band-gap reference uses only transistors and resistors, low noise and good long term stability result.

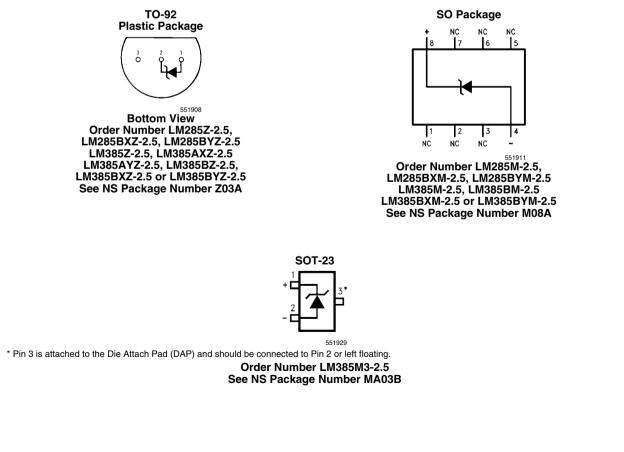
Careful design of the LM185-2.5 has made the device exceptionally tolerant of capacitive loading, making it easy to use in almost any reference application. The wide dynamic operating range allows its use with widely varying supplies with excellent regulation.

The extremely low power drain of the LM185-2.5 makes it useful for micropower circuitry. This voltage reference can be used to make portable meters, regulators or general purpose analog circuitry with battery life approaching shelf life. Further, the wide operating current allows it to replace older references with a tighter tolerance part. For applications requiring 1.2V see LM185-1.2.

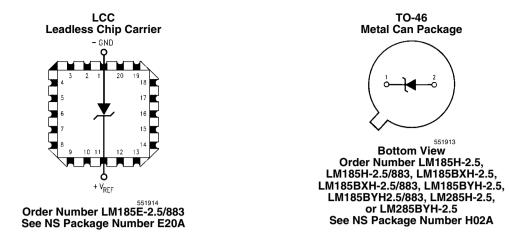
The LM185-2.5 is rated for operation over a  $-55^{\circ}$ C to  $125^{\circ}$ C temperature range while the LM285-2.5 is rated  $-40^{\circ}$ C to  $85^{\circ}$ C and the LM385-2.5 0°C to 70°C. The LM185-2.5/LM285-2.5 are available in a hermetic TO-46 package and the LM285-2.5/LM385-2.5 are also available in a low-cost TO-92 molded package, as well as S.O. and SOT-23. The LM185-2.5 is also available in a hermetic leadless chip carrier package.

## Features

- ±20 mV (±0.8%) max. initial tolerance (A grade)
- Operating current of 20 µA to 20 mA
- 0.6Ω dynamic impedance (A grade)
- Low temperature coefficient
- Low voltage reference—2.5V
- 1.2V device and adjustable device also available— LM185-1.2 series and LM185 series, respectively



# Connection Diagrams



# LM185-2.5/LM285-2.5/LM385-2.5

## Absolute Maximum Ratings (Notes 1, 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Reverse Current	30 mA
Forward Current	10 mA
Operating Temperature Range (Note 3)	
LM185-2.5	–55°C to + 125°C
LM285-2.5	-40°C to + 85°C
LM385-2.5	0°C to 70°C

## **Electrical Characteristics**

(Note 4)

ESD Susceptibility (Note 9)	2kV
Storage Temperature	–55°C to + 150°C
Soldering Information	
TO-92 Package (10 sec.)	260°C
TO-46 Package (10 sec.)	300°C
SO and SOT Package	
Vapor Phase (60 sec.)	215°C
Infrared (15 sec.)	220°C

See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices.

Parameter	Conditions	Tur	LM38 LM385 LM385	Units				
Farameter	Conditions	Тур	Tested Limit (Note 5)	Design Limit (Note 6)	(Limits)			
Reverse Breakdown	I <sub>R</sub> = 100 μA	2.500	2.480		V(Min)			
Voltage		2.500	2.520	2.470 2.530	V(Max) V(Min) V(Max)			
Minimum Operating Current		12	18	20	μA (Max)			
Reverse Breakdown Voltage Change with	$I_{MIN} \le I_R \le 1mA$		1	1.5	mV (Max)			
Current	$1 \text{ mA} \leq I_{\text{R}} \leq 20 \text{ mA}$		10	20	mV (Max)			
Reverse Dynamic Impedance	I <sub>R</sub> = 100 μA, f = 20 Hz	0.2		0.6 <b>1.5</b>	Ω			
Wideband Noise (rms)	I <sub>R</sub> = 100 μA 10 Hz ≤ f ≤ 10 kHz	120			μV			
Long Term Stability	I <sub>R</sub> = 100 μA, T = 1000 Hr, T <sub>A</sub> = 25°C ±0.1°C	20			ppm			
Average Temperature Coefficient (Note 7)	I <sub>MIN</sub> ≤ I <sub>R</sub> ≤ 20 mA X Suffix Y Suffix All Others		30 50	150	ppm/°C (Max)			

Electrical C	Characteristic	S							
Parameter	Conditions	Тур	LM185-2. LM185BX- LM185BY- LM285-2. LM285BX- LM285BY- Tested	2.5 2.5 .5 2.5	LM385	5B-2.5 BX-2.5 BY-2.5 Design	LM38 Tested	5-2.5 Design	Units (Limit)
			Limit	Limit	Limit	Limit	Limit	Limit	
			(Notes 5, 8)	(Note 6)	(Note 5)	(Note 6)	(Note 5)	(Note 6)	
Reverse Breakdown	T <sub>A</sub> = 25°C,	2.5	2.462		2.462		2.425		V(Min)
Voltage	20 µA ≤ I <sub>R</sub> ≤ 20 mA		2.538		2.538		2.575		V(Max)
Minimum Operating		13	20	30	20	30	20	30	μA
Current	LM385M3-2.5						15	20	(Max)
Reverse Breakdown Voltage	20 µA ≤ I <sub>R</sub> ≤ 1 mA		1	1.5	2.0	2.5	2.0	2.5	mV (Max)
Change with Current	1 mA ≤ I <sub>R</sub> ≤ 20 mA		10	20	20	25	20	25	mV (Max)
Reverse Dynamic Impedance	I <sub>R</sub> = 100 μA, f = 20 Hz	1							Ω
Wideband Noise (rms)	Ι <sub>R</sub> = 100 μΑ,	120							μV
	10 Hz ≤ f ≤ 10 kHz								
Long Term Stability	I <sub>R</sub> = 100 μA, T = 1000 Hr, T <sub>A</sub> = 25°C ±0.1°C	20							ppm
Average	I <sub>R</sub> = 100 μA								
Temperature Coefficient (Note 7)	X Suffix Y Suffix All Others		30 50	150	30 50	150		150	ppm/°C ppm/°C ppm/°C (Max)

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed.

Note 2: Refer to RETS185H-2.5 for military specifications.

Note 3: For elevated temperature operation,  $T_{JMAX}$  is:

LM185 150°C

LM285 125°C

LM385 100°C

Thermal Resistance	TO-92	TO-46	SO-8	SOT-23
$\theta_{ia}$ (Junction to Ambient)	180°C/W (0.4 Leads)	440°C/W	165°C/W	283°C/W
	170°C/W (0.125 Leads)			
$\theta_{jc}$ (Junction to Case)	N/A	80°C/W	N/A	N/A

Note 4: Parameters identified with boldface type apply at temperature extremes. All other numbers apply at  $T_A = T_J = 25^{\circ}C$ .

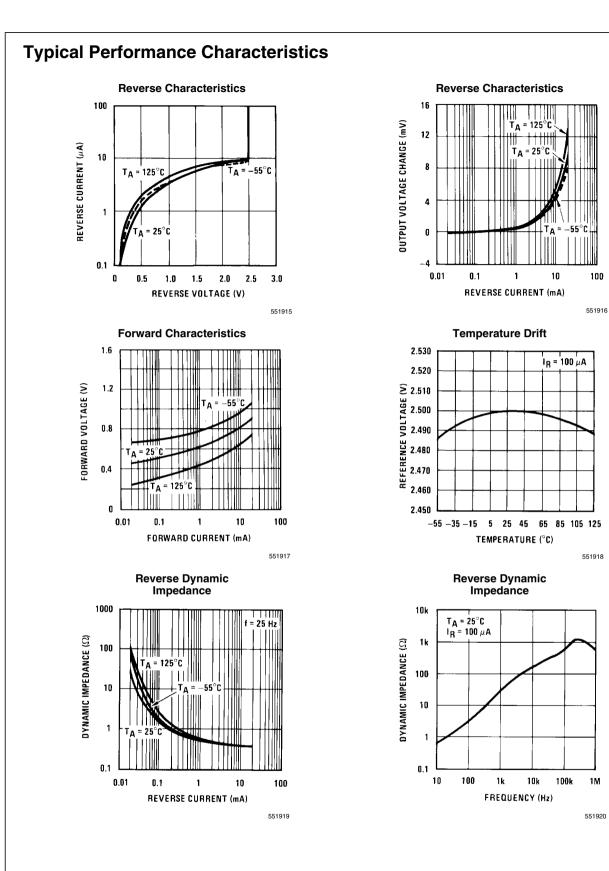
Note 5: Guaranteed and 100% production tested.

Note 6: Guaranteed, but not 100% production tested. These limits are not used to calculate average outgoing quality levels.

Note 7: The average temperature coefficient is defined as the maximum deviation of reference voltage at all measured temperatures between the operating  $T_{MAX}$  and  $T_{MIN}$ , divided by  $T_{MAX}$ - $T_{MIN}$ . The measured temperatures are -55°C, -40°C, 0°C, 25°C, 70°C, 85°C, 125°C.

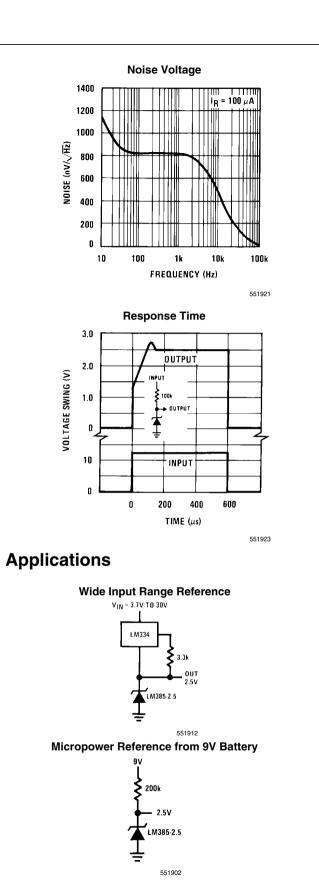
Note 8: A military RETS electrical specification available on request.

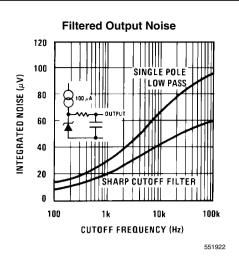
Note 9: The human body model is a 100 pF capacitor discharged through a 1.5 k $\!\Omega$  resistor into each pin.



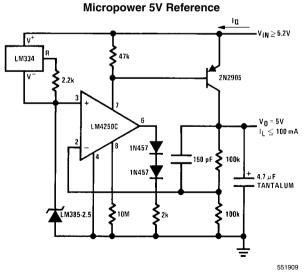
LM185-2.5/LM285-2.5/LM385-2.5



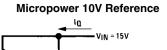


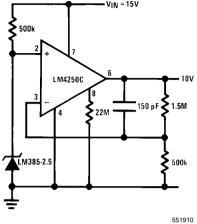


LM385-2.5 Applications



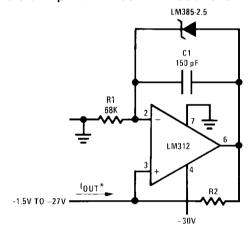
**Note 10:** I<sub>Q</sub> ≃ 40 μA



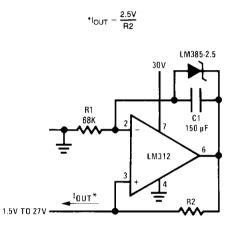


Note 11:  $I_Q \approx 30 \ \mu A$  standby current





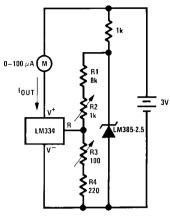
551924



551925

## METER THERMOMETERS

## 0°C–100°C Thermomemter

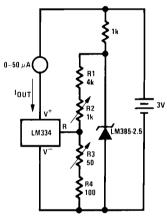


551926

## Calibration

1. Short LM385-2.5, adjust R3 for  $I_{OUT}$ =temp at 1µA/°K Remove short, adjust R2 for correct reading in centigrade



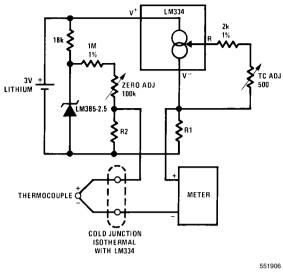


551927

#### Calibration

1. Short LM385-2.5, adjust R3 for  $I_{OUT} = temp$  at 1.8  $\mu A/^{\circ} K$  Remove short, adjust R2 for correct reading in  $^{\circ} F$ 

## Micropower Thermocouple Cold Junction Compensator

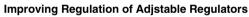


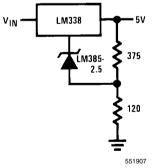
## **Adjustment Procedure**

- 1. Adjust TC ADJ pot until voltage across R1 equals Kelvin temperature multiplied by the thermocouple Seebeck coefficient.
- 2. Adjust zero ADJ pot until voltage across R2 equals the thermocouple Seebeck coefficient multiplied by 273.2.

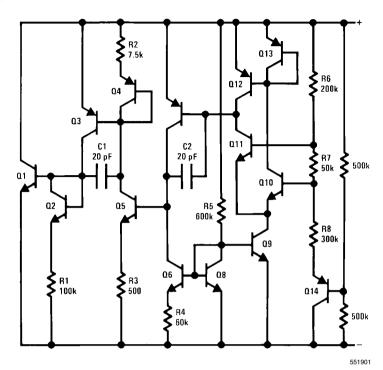
Thermocouple Type	Seebeck Co- efficient ( <sub>u</sub> V/°C)	R1 (Ω)	R2 (Ω)	Voltage Across R1 @25°C (mV)	Voltage Across R2 (mV)
J	52.3	523	1.24k	15.60	14.32
Т	42.8	432	1k	12.77	11.78
К	40.8	412	953Ω	12.17	11.17
S	6.4	63.4	150Ω	1.908	1.766

Typical supply current 50 µA

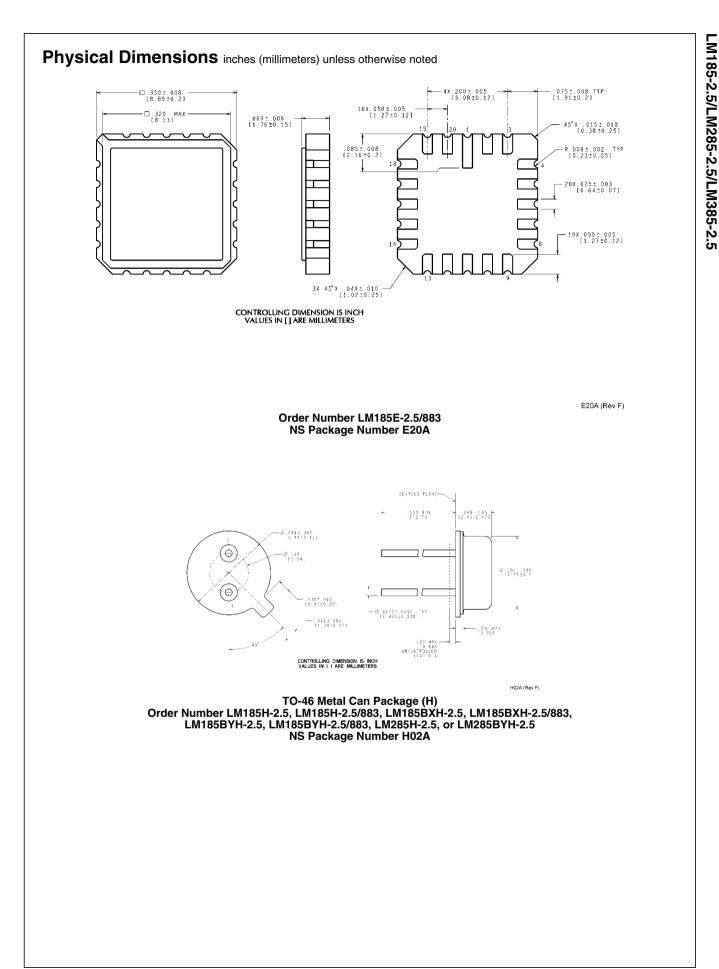




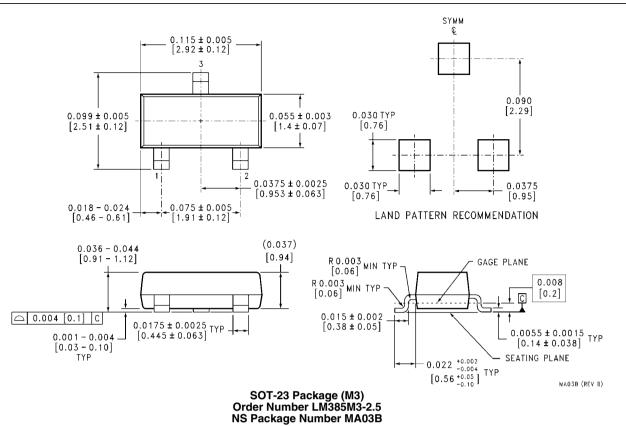
## Schematic Diagram

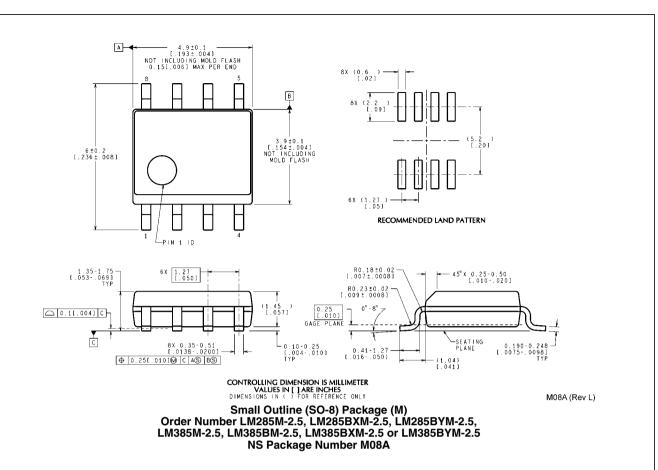


LM185-2.5/LM285-2.5/LM385-2.5

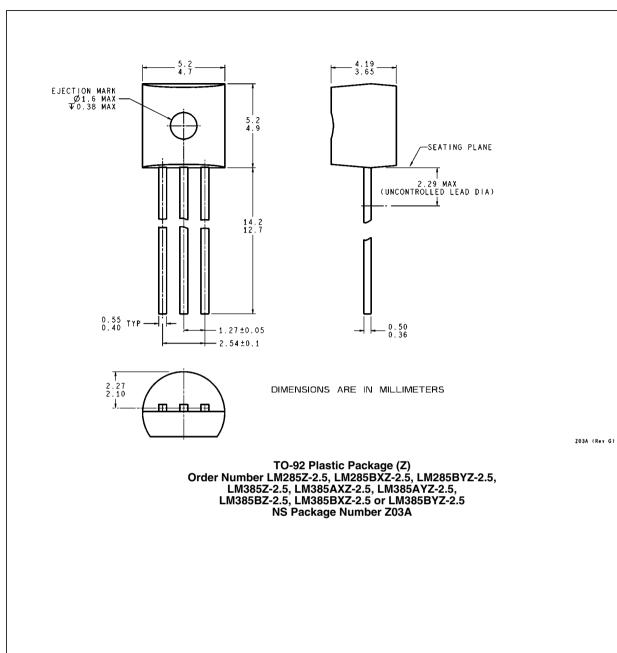








LM185-2.5/LM285-2.5/LM385-2.5



# Notes

# Notes

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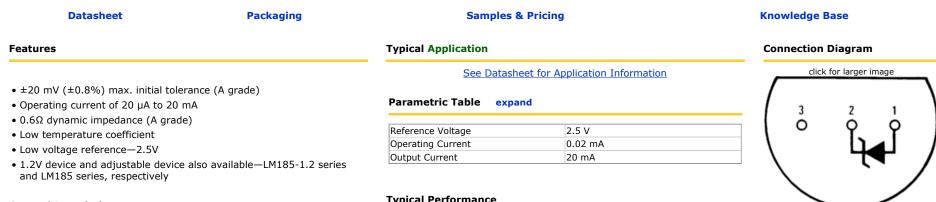
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## LM185-2.5 - Micropower Voltage Reference Diode

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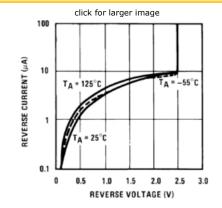
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**General Description** 

The LM185-2.5/LM285-2.5/LM385-2.5 are micropower 2-terminal bandgap voltage regulator diodes. More...

#### **Typical Performance**



## Datasheet

Rons Compliance Information	Size in Kbytes	Date		SOE	
LM185-2.5/LM285-2.5/LM385-2.5 Micropower Voltage Reference Diode	334 Kbytes	30-Jan-08	View Online	Download	Receive via Email
LM185-2.5QML Micropower Voltage Reference Diode	647 Kbytes	8-Nov-05	View Online	Download	Receive via Email

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## Package Availability, Models, Samples & Pricing

				Packa	ge			Factory Lea	d Time		Samples &	Budg	etary Pricing	Std	Package	
Part Number	Туре	Pins	Spec.	MSL Rating	Peak Reflow	RoHS Report	CAD Symbols	Weeks	Qty	Models	Electronic Orders	Qty	\$US each	Pack Size	Marking Format	
	TO-46	2	STD	4	NA	RoHS	N/A	Full produ	ction	N/A		1K+	\$15.60	box	NSXYTTE#	
LM185BXH-2.5	10-46	2	SID	1	INA	ROHS	N/A	6 weeks	2000	N/A		IK+	\$15.60	of 1000	LM185BXH-2.5	
LM185BYH-2.5	TO-46	2	STD	1	NA	RoHS	N/A	Full produ	ction	N/A		1K+	\$12.50	box of	NSXYTTE# LM185BYH-2.5	
LM103B11-2.5	10-40	2	510	L	NA .	KUIIS	N/A	6 weeks	2000	N/A		INT	\$12.JU	1000	NSATTL# LMIOSDIT-2.5	
5962-8759406XA	TO-46	2				RoHS	N/A	Obsolet	e	N/A		50+	\$18.00	tray of	NSZSSXXYYA 8759406XA Q	
(LM185BYH2.5-SMD)	10-40					KUIIS	N/A	10 weeks	500	N/A		70+	\$10.00	20	N3233AATTA 8739400AA Q	
LM185BYH2.5/883	TO-46	2	STD	1	NA	RoHS	N/A	Full produ	ction	N/A		50+	\$20.70	tray of	NSZSSXXYYA LM185BYH2.5 Q	
LINI 03 D 11 2.3/ 885	10-40	2	510	L	NA	KUIIS	N/A	8 weeks	100	N/A	Buy Now	704	\$20.70	20	N3233AATTA EM163BTT2.3 Q	
5962-8759402XA	TO-46	2				RoHS	N/A	Full produ	ction	N/A		50+	\$20.70	tray of	NSZSSXXYYA 8759402XA Q	
(LM185H-2.5-SMD)	10-40	2				RUHS	N/A	8 weeks	1000	N/A	Buy Now	50+	\$20.70	20	N3233XXTIA 0739402XA Q	
LM185H-2.5/883	TO-46	2	STD	1	NA	RoHS	N/A	Full produ	ction	N/A		50+	\$20.70	tray	NSZSSXXYYA LM185H-2.5 Q	
LM103H-2.3/003	10-40	2	510	L	NA	RUNS	N/A	8 weeks	500	N/A	Buy Now	50+	\$20.70	of 20	NS255XXTTA LM105H-2.5 Q	
								Lifetime l	ouy					tray	NS ZSSXXYYA	
LM185WG-2.5/883	CERPACK	10	STD	1	NA	RoHS	N/A			N/A	N/A		50+	\$21.60	of	8759402YA
								10 weeks	100					54	LM185WG- 2.5/883 Q	
5962-8759406VXA	TO 10					Delle		Full produ	ction			F0 /	+20C 00	tray		
(LM185BYH2.5-QV)	TO-46	2				RoHS	N/A	N/A	50	N/A		50+	\$296.00	of 20	NSZSSXXYYA 8759406VXA Q	
								Lifetime l	ouv					<b>h</b> 1101/	NS ZSSXXYYA	
LM185WG-2.5-QV	CERPACK	10	STD	1	NA	RoHS	N/A			N/A			CALL	tray of	8759402VY	
								N/A	500					N/A	A LM185W G-2.5-QV	
								Lifetime l	ouy				<u>cult</u>	tray		
LM185BYH2.5-MLS	TO-46	2				RoHS	N/A	N/A	N/A	N/A			CALL	of N/A	NSZSSXXYYALM185BYH2.5MLS	
	1					•	c	Full produ	ction				CALL	tray		
LM185-2.5 MD8			U	npackag	ea Die			N/A	2500	N/A			CALL	of N/A	-	

## **Obsolete Parts**

Obsolete Part	Alternate Part or Supplier	Source	Last Time Buy Date
LM185-2.5G MW8	NONE	NONE	09/08/99

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